## SARDAR PATEL UNIVERSITY

Programme: B.Sc Semester: IV

Syllabus with effect from: November - 2012

Paper Code: US04CELE01	Total Credit: 3
Title of Paper: Electronics Devices & Application	Total Credit: 5

Unit	Description in detail	Weightage (%)
I	Field Effect transistor & FET Biasing Circuits:- Decibel and frequency response, N & P channel JEFT, Characteristics of	
	JEFT, Parameters of JEFT, DC Load line & bias point, fixed voltage bias	25%
	circuit	
II	MOSFET & FET:- Self bias, Potential divider bias circuits, JFET Voltage amplifier, FET	25%
	Amplification, enhancement MOSFET, Depletion - enhancement -MOSFET , biasing MOSFETS.	2370
III	FET Circuits :-	
	Common source circuit and its as equivalent circuit, complete ac equivalent	
	circuit, Common drain circuit and its as equivalent circuit, complete ac	25%
	equivalent circuit, Common gate circuit and its ac equivalent circuit,	
	complete ac equivalent circuit.	
IV	Opto-electronics Devices 1 :-	
	Light units, Photo multiplier tube, Photo conductive cell, Light emitting	25%
	diode, Photo diode, solar cell, Photo-transistors, photo Darlington, Liquid	<i>23</i> /0
	crystal display, Opto electronics couplers, seven segment display.	

## **Basic Text & Reference Books:-**

- ➤ Electric engineering fundamentals, Vincent Deltore (2nd Edition)
- > Electronics devices and circuit, David Bell
- > Digital integrated electronics, Herbert Taub, Donald Schelling
- > Basic Electronics by Bhargava

